



#39/E
F. BELL
10-1001

Docket 740756-1838

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT Application of:)
Shunpei YAMAZAKI et al.) Art Unit 2822
Application Serial No. 09/118,010) Examiner M. Guerrero
Filed: July 17, 1998)
For: SEMICONDUCTOR DEVICE, METHOD)
OF FABRICATING THE SAME, AND)
ELECTROOPTICAL DEVICE)

AMENDMENT

Commissioner for Patents
Washington, D.C. 20231

Sir:

Responsive to the Office Action of **June 18, 2001**, the following amendments and remarks are respectfully submitted in connection with the above-identified application.

IN THE CLAIMS:

Please amend the claims as follows. Attached hereto is a marked-up copy of the amended claims.

1. (Three Times Amended) A semiconductor device comprising:
- a first resinous substrate having an uneven surface, a second resinous substrate opposed to said first resinous substrate, and a liquid crystal layer therebetween;
- a resinous layer provided on said uneven surface of said first resinous substrate and having a planarized surface;
- a thin film transistor provided on said planarized surface of said resinous layer;
- and
- an interlayer insulating layer comprising resinous material provided over said

NVA197251.1

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01 FC:103
02 FC:102

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242.00 CP

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